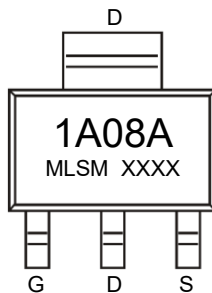


Features

- Low $R_{DS(on)}$ & FOM
- Extremely low switching loss
- Excellent stability and uniformity
- Fast switching and soft recovery

Application

- Consumer electronic power supply
- Motor control
- Synchronous-rectification
- Isolated DC/DC convertor



1A08A: Device code
 XXXX: Code

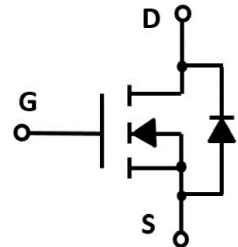
Marking and pin assignment

Product Summary

V_{DS}	$R_{DS(ON)}$ TYP	I_D
100V	90m Ω @10V	8A
	115m Ω @4.5V	



SOT-223 top view



Schematic diagram



Pb-Free



Halogen-Free

Absolute Maximum Ratings (TA=25°C unless otherwise noted)

Symbol	Parameter	Rating	Unit
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Common Ratings (TC=25°C Unless Otherwise Noted)

V_{DS}	Drain-Source Breakdown Voltage	100	V
V_{GS}	Gate-Source Voltage	± 20	V
T_J	Maximum Junction Temperature	150	°C
T_{STG}	Storage Temperature Range	-50 to 155	°C
I_S	Diode Continuous Forward Current	$T_C=25^\circ\text{C}$ 8	A

Mounted on Large Heat Sink

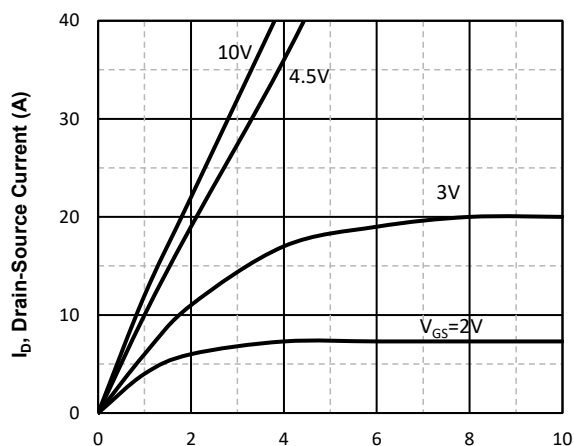
I_{DM}	Pulse Drain Current Tested	$T_C=25^\circ\text{C}$ 30	A
I_D	Continuous Drain Current	$T_C=25^\circ\text{C}$ 8	A
P_D	Maximum Power Dissipation	$T_C=25^\circ\text{C}$ 2.5	W
$R_{\theta JA}$	Thermal Resistance Junction-Ambient	100	°C/W

Ordering Information (Example)

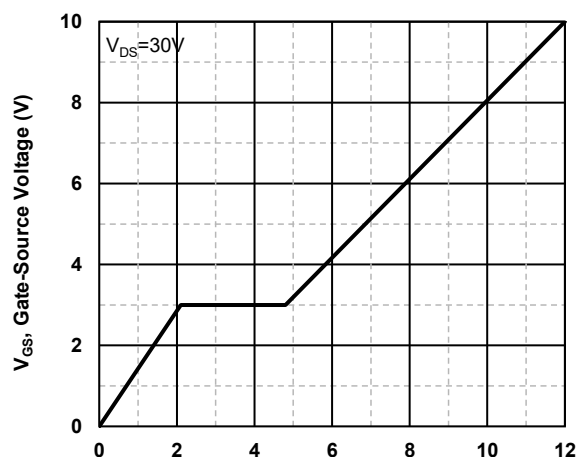
Type	Package	Marking	Minimum Package(pcs)	Inner Box Quantity(pcs)	Outer Carton Quantity(pcs)	Delivery Mode
MT1A08A	SOT-223	1A08A	2,500	5,000	35,000	13"reel

Electrical Characteristics (T _J =25°C unless otherwise noted)						
Symbol	Parameter	Condition	Min	Typ	Max	Unit
Static Electrical Characteristics @ T _J = 25°C (unless otherwise stated)						
B _{V(BR)DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V, I _D =250μA	100	--	--	V
I _{DSS}	Zero Gate Voltage Drain Current	V _{DS} =100V, V _{GS} =0V	--	--	1.0	μA
I _{GSS}	Gate-Body Leakage Current	V _{GS} =±20V, V _{DS} =0V	--	--	±100	nA
V _{GS(th)}	Gate Threshold Voltage	V _{DS} =V _{GS} , I _D =250μA	1.0	1.5	2.5	V
R _{DS(on)}	Drain-Source On-State Resistance	V _{GS} =10V, I _D =4A	--	90	120	mΩ
		V _{GS} =4.5V, I _D =2A	--	115	180	mΩ
Dynamic Electrical Characteristics @ T _J = 25°C (unless otherwise stated)						
C _{ISS}	Input Capacitance	V _{DS} =25V, V _{GS} =0V, f=1MHz	--	760	--	pF
C _{OSS}	Output Capacitance		--	38	--	pF
C _{RSS}	Reverse Transfer Capacitance		--	33	--	pF
Switching Characteristics						
Q _g	Total Gate Charge	V _{DS} =30V, I _D =5A, V _{GS} =10V	--	12	--	nC
Q _{gs}	Gate Source Charge		--	2.2	--	nC
Q _{gd}	Gate Drain Charge		--	2.5	--	nC
t _{d(on)}	Turn-on Delay Time	V _{DS} =30V, I _D =10A, V _{GS} =10V, R _G =1.8Ω	--	7	--	nS
t _r	Turn-on Rise Time		--	5	--	nS
t _{d(off)}	Turn-Off Delay Time		--	15	--	nS
t _f	Turn-Off Fall Time		--	6	--	nS
Source- Drain Diode Characteristics						
V _{SD}	Forward on voltage	T _J =25°C, I _S =8A	--	--	1.2	V

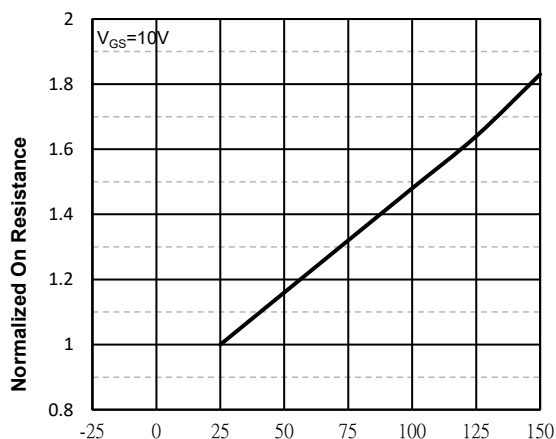
Typical Operating Characteristics



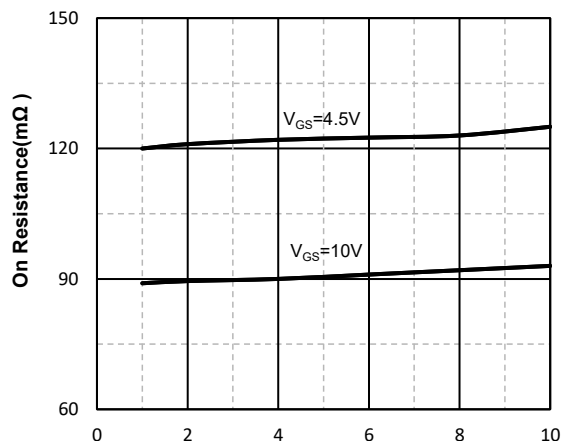
V_{DS} , Drain -Source Voltage (V)
Fig1. Typical Output Characteristics



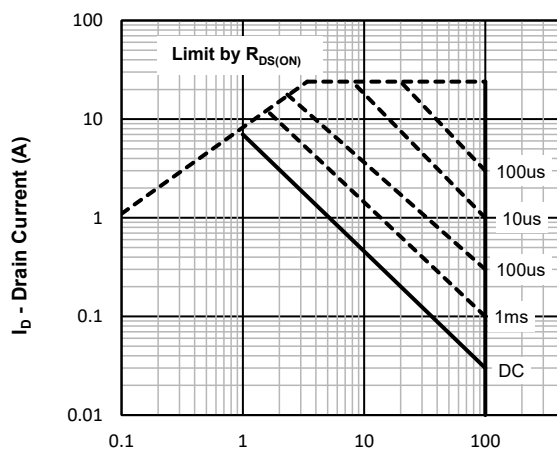
Q_g -Total Gate Charge (nC)
Fig2. Typical Gate Charge Vs. Gate-Source Voltage



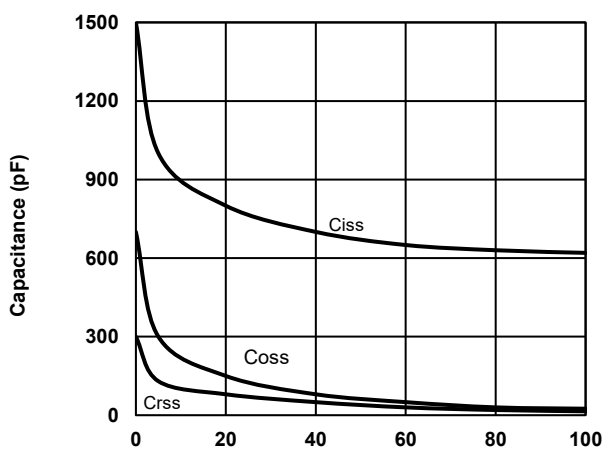
T_j - Junction Temperature ($^{\circ}C$)
Fig3. Normalized On-Resistance Vs. Temperature



I_D , Drain-Source Current (A)
Fig4. On-Resistance Vs. Drain-Source Current

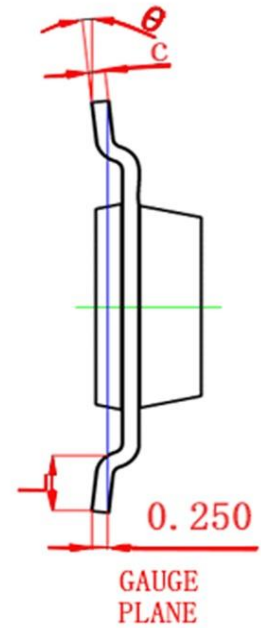
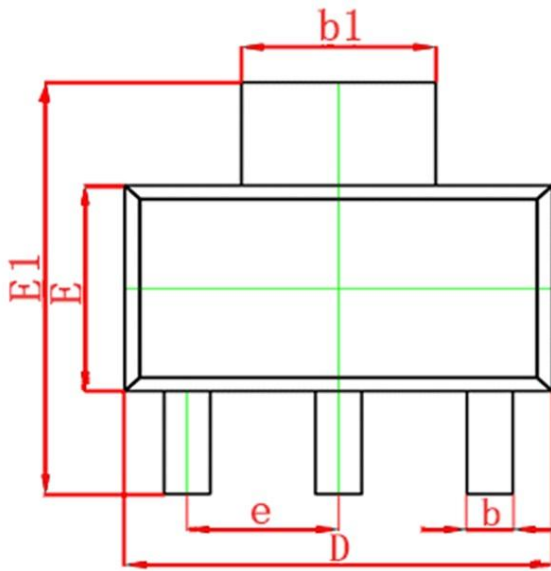


V_{DS} , Drain -Source Voltage (V)
Fig5. Maximum Safe Operating Area



V_{DS} , Drain-Source Voltage (V)
Fig6. Typical Capacitance Vs. Drain-Source Voltage

SOT-223 Package information



Symbol	Dimensions in Millimeters(mm)		Dimensions In Inches	
	Min	Max	Min	Max
A	--	1.800	--	0.071
A1	0.020	0.100	0.001	0.004
A2	1.500	1.700	0.059	0.067
b	0.660	0.840	0.026	0.033
b1	2.900	3.100	0.114	0.122
c	0.230	0.350	0.009	0.014
D	6.300	6.700	0.248	0.264
E	3.300	3.700	0.130	0.146
E1	6.700	7.300	0.264	0.287
e	2.300(BSC)		0.091(BSC)	
L	0.750	--	0.030	--
θ	0°	10°	0°	10°